AMAT Docket No. 2616 US/RTP/LE BSTZ Docket No. 004887 P090

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of:

Guangcai Xing, et al.

Application No. 09/298,064

Filed: April 22, 1999

APPARATUS AND METHOD FOR EXPOSING A SUBSTRATE TO PLASMA

RESPONSE TO FINAL OFFICE ACTION

Box Amendments - No Fee Assistant Commissioner for Patents

Washington, D.C. 20231

Dear Sir:

In response to the final Office Action mailed on November 6, 2002, Applicants respectfully request consideration of the following remarks.

IN THE CLAIMS

Presented herewith is a full set of the pending claims.

An apparatus comprising:

a first reaction chamber,

a gas source coupled to the first reaction chamber to supply a nitrogen gas to the first reaction chamber:

an excitation energy source coupled to the first reaction chamber to generate a nitrogen plasma comprising ions and radicals from the nitrogen gas; and

a second reaction chamber adapted to house a substrate for film formation at a site in the second reaction chamber.

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